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Future SiPM's developments

MEPhI&PULSAR

Silicon photomultiplier (SiPM)

Multy pixel device with common readout



Each pixel operates in self-quenching geiger mode Number of pixels: 1156 Recovery time/pixel R_{pixel}*C_{pixel}~100÷500 ns

One pixel - digital signal (0 or 1) SiPM at whole - analogue device





SiPMs in Tile HCAL prototype

Tile with milled groove for WLS and precise hole for SiPM installation

SiPMs 1156 pixels $1x1 \text{ mm}^2$ 3 5±0.03

Precise ceramic plate

The first HCAL prototype cassette



40 Cassettes will be required In framework of CALICE collaboration and ISTC project 3090

Typical HCAL prototype SiPM parameters



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MIP particles registration

MINICAL system 25 fired pixels/MIP

Source tests



5x5x0.5cm³ tile



For prototype SiPM-tile assembly

We have 15 pixels/MIP



3x3x0.5cm³ tile

Key's questions:

•Efficiency of MIP registration

•Noise registration probability

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Efficiency of MIP registration for different MIP signals and interpixel crosstalk (MC)



The dark rate of the SiPM for different gains in dependence on the level of the threshold



Crosstalk increases the manypixel firing probability

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We need to suppress crosstalk

Dependence of interpixel crosstalk on gain for different distance between pixels



Crosstalk protection





events



Efficiency of light registration 40%

SiPM radiational hardness

preliminary results

Under investigation at ITEP now:

protons

electrons

neutrons

gammas



SiPM's characteristics without irradiation and after 900 rad proton 200 MeV



SiPM single pixel spectra and MIP registration without irradiation and after 900 rad proton 200 MeV



New proposal for HCAL based on large SiPM

3x3mm SiPM parameters

Sensitive area : 3x3 mm2 # of pixels: 5625

- Depletion region: appr. 1 μm
- Pixel size: 30 μmx30 μm
- Working voltage: 20...25 V Gain: 1...2 ×10**6

Dark rate.room temperature: 20 MHz

SiPM noise(FWHM):

room temperature 5-8 electrons -50 C 0.4 electrons

- Single pixel recovery time: 1us After pulsing probability: appr. 1%
- Optical crosstalk: appr. 30 50 % ENF: appr. 1.5-2.0(overvoltage dependent)

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MIP signal for 3x3mm² SiPM

Plastic scintillator 30x30x5 mm³ without WLS fiber and 3x3 mm² SiPM assembly was tested at MEPhI (room temperature) with Sr90



3M



Efficiency of light registration appr18%

Appr. 30 fired pixels/MIP

Noise probability & Light Collection Uniformity for 3x3 mm² SiPM-tile assembly



3*10⁻⁵ * 8000=0,24 events/prototype

5x5 mm² SiPM



Under investigation now

SiPM: sensitive area $5.2x4.9 \text{ mm}^2$ Number of pixels 40x40=1600Active pixel area $100x100 \text{ }\mu\text{m}^2$ Period $130x120 \text{ }\mu\text{m}^2$



SiPM's future development

Tile 3x3 cm² Without WLS

SiPM,

 α -source

Without precision requirements to support plate

Without precision milling and assembling

Electronics

Without single pixel resolution

Self triggering

With internal delay

Efficiency of light registration 20%

Geometrical efficiency 25%

40 MHz Dark rate

Period **30x30** µm

Total number of pixels 27800

MIP signal 50 pixels

Noise signal (100 ns) 4 pixel Monitoring and calibration with SiPM:

Crosstalk suppression

Dynamic range 27800/50≈550

Fast signal ~ 5 ns

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Response functions for the SiPMs with different total pixel numbers measured for 40 ps laser pulses



- Monitoring by measurement of MIP or alpha signals No need single pixel spectra



Conclusions:

New generation of SiPM's with suppression of: optical crosstalk afterpulsing dark rate is under development now in order to obtain the SiPM's with: Area up to 10x10 mm2 PDE of 40-50% ENF=1.0...1.05 Subnanosecond timing It increases significantly the number of SiPM applications B.Dolgoshein, 'Large area SiPM's...' In framework of CALICE

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Emission spectrum for Vladimir scintillyator (POPOP)



Light Collection Uniformity,

Y11 MC 1mm fiber, Vladimir Scintillator, mated sides, 3M foil on top and bottom Reduction in light yield near tile edges is due to finite size of a β source



Light yield drop between tiles acceptable (Calorimeter geometry is not projective) Cross-talk between tiles ~2% - acceptable



Sufficient uniformity for a hadron calorimeter even for large tiles Acceptable cross-talk between tiles of ~2% per side Sufficient light yield of 17, 28, 21 pixels/mip for 12x12, 6x6, and 3x3 cm² tiles (quarter of a circle fiber in case of 3x3 cm² tile)

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Pixel/MIP distribution for SiPMs-tile-WLS assembly



Calibration of the SiPM

For SiPM saturation correction we need to know the value

Number_of_fired_pixels/MIP





LAL 18 ch. SiPM FE chip CALICE DAQ board for 8 planes (UK groups)



Temperature and bias voltage dependence: delta T(V) Gain Signal=Gain x PDE x Crosstalk -1 C +2.2% +4.5% +0.1V +4.3% +7%



SiPMs parameters

